

SIC SCHOTTKY DIODE TYPE 2×75A

Features

• High surge current capable

· Zero reverse recovery Zero forward recovery

• Isolation type package

• Temperature independent switching behavior

1200 V • V_{DC}

2×75 A • **I**F (Tc<135°C)

Benefits

Unipolar rectifier

• Higher efficiency

· Smaller heat sink

Applications

· Motor drives

• Switch mode power supplies

· Ev chargers

· Solar inverters

· Welding equipment

· Power factor correction

• Diode snubber

Automotive

· induction heating

Maximum Ratings

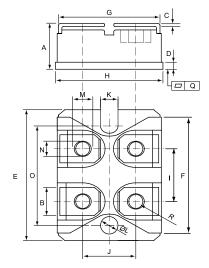
Operating Junction Temperature : -55°C to +175°C

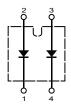
Storage Temperature : -55°C to +175°C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×75-120P3B	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I _F	I _F T _C =135 °C			
Surge non-repetitive forward current	I _{FSM}	T _C =25 °C, t _p =8.3 ms	600		
sine halfwave (per diode)	1 GIVI	T _C =150 °C, t _p =8.3 ms	375	Α	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t_p =10 μ s	2400	2400	
(per diode)		T_{C} =150 °C, t_{p} =10 μ s	1500		
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	1200	٧	
Isolation voltage (between All Terminals and Baseplate)	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA	2500	٧	
Mounting torque	Md	To heatsink	1.3	Nm	
Mounting torque	IVIG	To terminal	1.1		







parallel

DIMENSIONS					
	INCHES		MM		
	MIN	MAX	MIN	MAX	
Α	0.460	0.483	11.68	12.28	
В	0.307	0.323	7.80	8.20	
С	0.030	0.033	0.75	0.85	
D	0.071	0.081	1.80	2.05	
Е	1.488	1.504	37.80	38.20	
F	1.248	1.260	31.70	32.00	
G	0.917	0.957 23.30		24.30	
Н	0.996	1.008	25.30	25.60	
I	0.579	0.602 14.70		15.30	
J	0.492	0.516	12.50 13		
K	0.161	0.169	9 4.10 4		
L	0.161	0.169	0.169 4.10		
М	0.181	0.197 4.60		5.00	
N	0.165	0.181	4.20	4.60	
0	1.181	1.197	30.00	30.40	
Q	-0.002	0.004	-0.05	0.10	
R	M4*8				



Electrical Characteristics, at T_i=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V_{DC}		1,200	-	-	٧
Diode forward voltage	V _F	I _F =75A, T _J =25 °C	-	1.5	1.7	V
		I _F =75A, T _J =175 °C	-	2.3	2.8	
Reverse current	I _R	V _R =1,200V, T _J =25 °C	-	20	40	μΑ
		V _R =1,200V, T _J =175 °C	-	60	270	

AC Characteristics (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	di/dt =1100A/µs IF = 75A, VR =800V	-	280	-	nC
Total capacitance	С	V _R =0V, f=1 MHz T _J =25 °C	-	4,286	-	pF
		V _R =400V, f=1 MHz T _J =25 °C	-	345	-	
		V _R =800V, f=1 MHz T _J =25 °C	-	245	-	

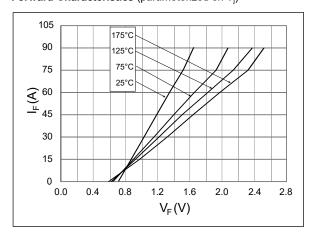
Thermal Characteristics (per diode)

Static Characteristics	Cumbal	Values	Unit	
Static Characteristics	Symbol	typ.		
Thermal resistance from junction to case	$R_{ heta JC}$	0.18	°C/W	

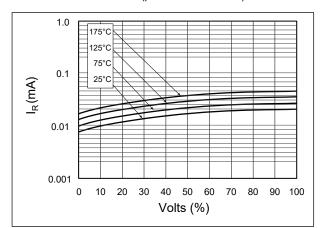


Typical Performance

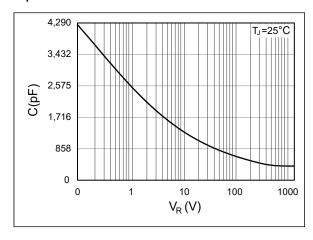
Forward Characteristics (parameterized on T_j)



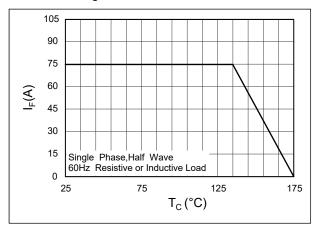
Reverse Characteristics (parameterized on TJ)



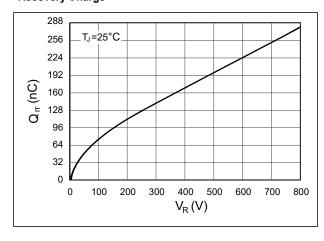
Capacitance



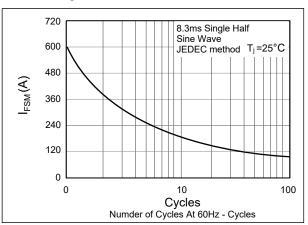
Current Derating



Recovery Charge



Forward Surge Current





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